BEEE102L	Course Title		3	Т	Р	С				
	0 0				0	3				
Pre-requisite	NIL	Syll	abu		ersi	on				
1.0										
Course Objectiv	es e									
 Familiarize with various laws and theorems to solve electric and electronic circuits Provide an overview on working principle of machines Excel the concepts of semiconductor devices, op-amps and digital circuits 										
Course Outcomes										
On completion of	the course, the students will be able to:									
2. Comprehend th3. Classify and co4. Design basic or	nd AC circuit parameters using various laws and theorer ne parameters of magnetic circuits impare various types of electrical machines and its applicational circuits in digital system aracteristics and applications of semiconductor devices		าร							
-										
Module:1 DC C					hou					
connection of ci	ments and sources; Ohms law; Kirchhoff's laws; S rcuit elements; Star-delta transformation; Mesh curre Theorems: Thevenin's, Maximum power transfer	ent a	nalys	sis;	No	de				
Module:2 AC C	ircuits			8	hou	ırs				
RLC series circu	es and currents, RMS, average, maximum values, Sin ts, Power in AC circuits, Power Factor, Three phase nnections, Electrical Safety, Fuses and Earthing.									
Module:3 Mag	netic Circuits			7	hοι	ırs				
	Toroidal core: Flux density, Flux linkage; Magnetic lies and parallel circuits; Self and mutual inductance; Tra									
	trical Machines			7	hou	ırs				
phase Induction	rking principle and applications of DC Machines, Tr motors, synchronous generators, single phase inducti motor, universal motor and BLDC motor.									
				_	hou	ırs				
Module:5 Digit	•			1						
	; Number base conversion; Boolean algebra: simplif K-maps; Logic gates; Design of basic combinationa nultiplexers.			В		an				
Binary arithmetic functions using multiplexers, de-r	K-maps; Logic gates; Design of basic combinations			: B		ers,				
Binary arithmetic functions using multiplexers, de-r Module:6 Semi Characteristics: F	K-maps; Logic gates; Design of basic combinations	al cir	cuits	Be a	dde hou	an ers, urs				
Binary arithmetic functions using multiplexers, de-r Module:6 Semi Characteristics: F	K-maps; Logic gates; Design of basic combinations nultiplexers. conductor Devices and Applications N junction diode, Zener diode, BJT, MOSFET; App	al cir	cuits	: Be : a 7 Re	dde hou	ers, urs ier,				
Binary arithmetic functions using multiplexers, de-r Module:6 Semi Characteristics: F Voltage regulator	K-maps; Logic gates; Design of basic combinations nultiplexers. conductor Devices and Applications PN junction diode, Zener diode, BJT, MOSFET; Applicational amplifier.	al cir	cuits	: Be : a 7 Re	hou ectifi	ers, urs ier,				
Binary arithmetic functions using multiplexers, de-r Module:6 Semi Characteristics: F Voltage regulator Module:7 Cont	K-maps; Logic gates; Design of basic combinations nultiplexers. conductor Devices and Applications PN junction diode, Zener diode, BJT, MOSFET; Applicational amplifier.	al cire	ons:	7 Re	hou ectifi	ers, urs ier,				
Binary arithmetic functions using multiplexers, de-regulator Characteristics: For Voltage regulator Module:7 Cont	K-maps; Logic gates; Design of basic combinational nultiplexers. conductor Devices and Applications PN junction diode, Zener diode, BJT, MOSFET; Apple Operational amplifier. emporary Issues Total Lecture hours:	al circ	ons:	7 R€	hou hou hou	ean ers, urs er, urs				
Binary arithmetic functions using multiplexers, de-r Module:6 Semi Characteristics: Foots Voltage regulator Module:7 Cont Text Books 1 Allan R. Har Pearson Edu	K-maps; Logic gates; Design of basic combinations nultiplexers. conductor Devices and Applications PN junction diode, Zener diode, BJT, MOSFET; Apple Operational amplifier. emporary Issues Total Lecture hours:	al circ	ons:	7 R€	hou hou hou	ean ers, urs er, urs				

R. L. Boylestad and L. Nashelsky, Electronic Devices and Circuit Theory, 11th edition.

Reference Books

	Pearson, 2012						
2	DP Kothari & Nagrath, "Basic Electric Engineering", 2019, Tata McGraw Hill						
Recommended by Board of Studies		28-05-2022					
Approved by Academic Council		No. 67	Date	08-08-2022			